



Micro Commercial Components 20736 Marilla Street Chatsworth CA 91311

Phone: (818) 701-4933 Fax: (818) 701-4939

## **MCU60N08**

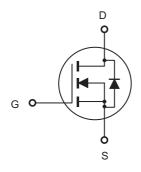
## **Features**

- Excellent package for good heat dissipation
- High density cell design for ultra low Rdson
- Halogen free available upon request by adding suffix "-HF"
- Excellent package for good heat dissipation
- Special process technology for high ESD capability
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level 1

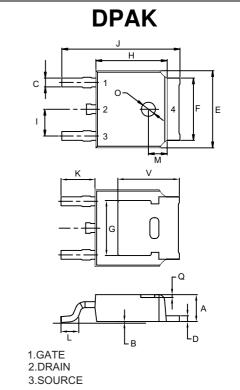
### Maximum Ratings @ 25°C Unless Otherwise Specified

Symbol	Parameter	Rating	Unit
$V_{DS}$	Drain-source Voltage	80	V
I <sub>D</sub>	Drain Current-Continuous	60	Α
E <sub>AS</sub>	Single Pulsed Avalanche Energy(note1)	300	mJ
$V_{GS}$	Gate-source Voltage	±20	V
I <sub>DM</sub>	Pulsed Drain Current	240	Α
$R_{_{\scriptscriptstyle{\theta}JA}}$	Thermal Resistance Junction to Ambient	100	°C∕W
TJ	Operating Junction Temperature -55 to +150		$^{\circ}$
T <sub>STG</sub>	Storage Temperature	-55 to +150	$^{\circ}$

## **Internal Block Diagram**



# N-Channel Enhancement Mode Field Effect Transistor



DIMENSIONS					
	INCHES		MM		
DIM	MIN	MAX	MIN	MAX	NOTE
Α	0.087	0.094	2.20	2.40	
В	0.000	0.005	0.00	0.13	
С	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
Е	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		
Н	0.236	0.244	6.00	6.20	
I	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
K	0.114		2.90		
L	0.055	0.067	1.40	1.70	
M	0.063		1.60		
0	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
	0.211		5.35		



## Electrical characteristics (T<sub>a</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Off characteristics						
Drain-source breakdown voltage	V(BR) DSS	V <sub>G</sub> S = 0V, I <sub>D</sub> =250μA	80			٧
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> =80V, V <sub>GS</sub> =0V			1	μA
Gate-body leakage current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±100	nA
On characteristics (note2)						
Gate-threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	2	3	4	٧
Static drain-source on-sate resistance	RDS(on)	V <sub>GS</sub> =10V, I <sub>D</sub> =30A		7.0	8.5	mΩ

Dynamic characteristics (note 3)					
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V, f =1MHz	4400		pF
Output capacitance	C <sub>oss</sub>		340		
Reverse transfer capacitance	$C_{rss}$		260		
Switching characteristics (note 3)			·		
Total gate charge	Qg	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =30A	100		nC
Gate-source charge	$Q_gs$		20		
Gate-drain charge	$Q_{gd}$		30		
Turn-on delay time	t <sub>d(on)</sub>	$V_{DD}$ =30V, $V_{GS}$ =10V, $R_{G}$ =2.5 $\Omega$ , $I_{D}$ =2A, $R_{L}$ =15 $\Omega$	18		- ns
Turn-on rise time	tr		12		
Turn-off delay time	td(off)		56		
Turn-off fall time	<b>t</b> f		15		
Drain-Source Diode Characteristics			·		
Drain-source diode forward voltage(note2)	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =30A		1.2	٧
Continuous drain-source diode forward current	Is			60	А
Pulsed drain-source diode forward current	I <sub>SM</sub>			240	Α

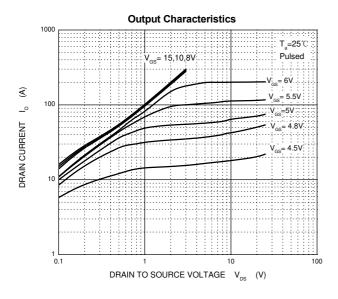
### Notes:

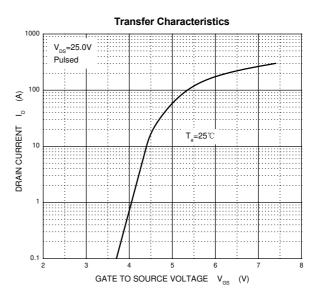
- 1. L=0.5mH,V<sub>DD</sub>=40V,V<sub>G</sub>=10V,R<sub>G</sub>=25 $\Omega$ ,Starting T<sub>J</sub>=25 $^{\circ}$ C.
- 2. Pulse Test : Pulse Width≤300µs, duty cycle ≤2%.
- 3. Guaranteed by design, not subject to production.

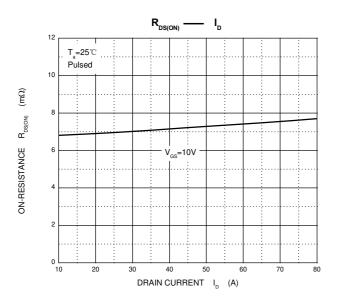


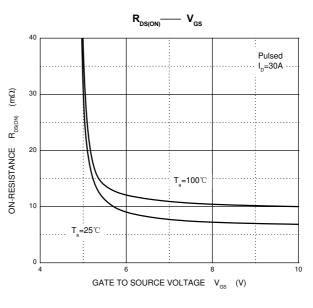
## **Typical Characteristics**

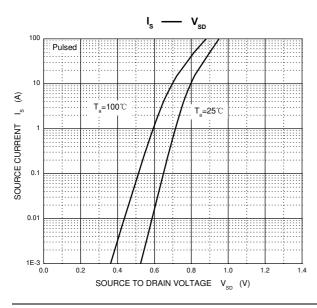
## **Micro Commercial Components**

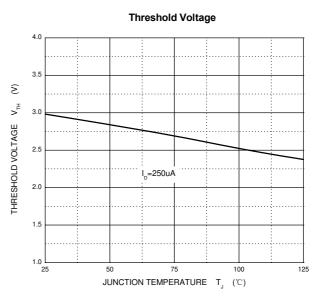














#### **Micro Commercial Components**

## **Ordering Information:**

Device	Packing
Part Number-TP	Tape&Reel:2.5Kpcs/Reel

Note: Adding "-HF" suffix for halogen free, eg. Part Number-TP-HF

#### \*\*\*IMPORTANT NOTICE\*\*\*

**Micro Commercial Components Corp.** reserves the right to make changes without further notice to any product herein to make corrections, modifications, enhancements, improvements, or other changes. **Micro Commercial Components Corp.** does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold **Micro Commercial Components Corp.** and all the companies whose products are represented on our website, harmless against all damages.

#### \*\*\*LIFE SUPPORT\*\*\*

MCC's products are not authorized for use as critical components in life support devices or systems without the express written approval of Micro Commercial Components Corporation.

#### \*\*\*CUSTOMER AWARENESS\*\*\*

Counterfeiting of semiconductor parts is a growing problem in the industry. Micro Commercial Components (MCC) is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. MCC strongly encourages customers to purchase MCC parts either directly from MCC or from Authorized MCC Distributors who are listed by country on our web page cited below. Products customers buy either from MCC directly or from Authorized MCC Distributors are genuine parts, have full traceability, meet MCC's quality standards for handling and storage. MCC will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. MCC is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.